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# Thermodynamic Model to Study Removal of Chlorine, Silicon Tetrafluoride and other Uncommon Materials from Off Gases

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Off-gasses of a process require treatment to either neutralize or remove the toxic constituents. To accurately remove different materials in a gaseous stream, their interaction with multiple components is important to understand. The economic and the environmental impact from the failure to do so would be significant. In a particular off gas, the effects of fluorides like HF and  $SiF_4$ ,  $SiO_2$  is studied in tandem with the presence of traditional off gas components like NOx and chlorine, particularly at low concentrations.

This work would be useful for several industries like chemicals and mining. Traditionally these off gasses are cleaned in scrubbers and the effluent is discharged. If the pH of the effluent is not regulated, the effluent could have a significant impact in the aquatic ecosystem. This makes prediction of  $NO_3^-$  and  $NO_2^-$  concentration in the effluent, very important. The thermodynamic model was developed to be used in scrubber modelling.

# 1. Thermodynamic Model

The pre-requisite for this simulation study is the development of a complete thermodynamic model that mimics the absorption reactions, while being simple to reduce the convergence issues. This chapter explains the thermodynamic model developed. The chapter focuses on NOx reactions in liquid and gaseous phase, the  $HF-SiF_4-H_2O$  system and  $SiO_2$  precipitation. The model was developed in Aspen Plus V7.3 (AspenTech) and ELECNRTL thermodynamic model was used (Chen C.C, et al, 1982). For interaction between the chloride and carbonate species, ASPEN's default reaction definitions in ELECNRTL model are used.

# 1.1 Fluoride absorption in water and SiO<sub>2</sub> Precipitation

The main fluoride compounds in the off gas are SiF<sub>4</sub> (Silicon Tetrafluoride) and HF (Hydrogen Fluoride). Both these compounds are highly soluble in water. Hydrogen fluoride absorption in water results in a solution of weak acid. The ionization constant of this solution is  $7.4 \times 10^{-4}$  at 25 °C making it slightly stronger than Acetic acid (Kohl A.L., Nielson R.,1997). The mechanism for absorption of SiF<sub>4</sub> available in literature is as follows

$$SiF_4 + H_2O \iff SiO_2 + 4HF$$
 (1)

$$SiF_4 + 2HF \implies H_2SiF_6$$

There is precipitation of SiO<sub>2</sub> at very low concentrations of  $H_2SiF_6$  and as the concentration increases, solubility increases. The solubility of SiO<sub>2</sub> in water is very low at infinite dilution of  $H_2SiF_6$ . This effect is modeled as a salt precipitation reaction. Hence to begin with, soluble SiO<sub>2</sub> is produced from the reaction (1) and solid silica is then produced via,

$$SiO_2 \implies SiO_2(s)$$
 (3)

The kinetic constant of this equation is predicted from literature data (Thomsen S.M,1952) There is an apparent increase in the solubility of SiO2 with increase in pH (Iler R.K., 1979). This effect is modeled through the following reaction.

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325

(2)

$$SiO_2 + 2H_2O \leftarrow HSiO_3 + H_3O^+$$

The net soluble SiO<sub>2</sub> is the sum of SiO<sub>2</sub> in liquid and the  $HSiO_3^-$  ion.

#### 1.2 NOx reaction model

To simplify for NOx absorption, an NO oxidation model has been used to represent the overall NOx absorption in the scrubber. This model has been developed by ASPEN Tech and is available ready to use open source. Three gas phase reactions are used to predict the behaviour of NOx.

(4)

(5)

(7)

Nitric oxide undergoes a slow homogeneous reaction with oxygen to yield nitrogen dioxide

$$2NO + O_2 \iff 2NO_2$$

The kinetics for this reaction is not well defined. The commonly accepted third-order rate expression is valid if  $NO_3$  is the only reaction intermediate. From Fluor experience, it is recommended use the traditional Bodenstein third-order rate expression (Bodenstien M., 1922): The chemical equilibrium constant of the oxidation reaction has been obtained from Aspen Plus.

The second reaction is the dimerization of the produced NO<sub>2</sub>.

$$2NO_2 \rightleftharpoons N_2O_4$$
 (6)

In this simulation, the reaction is assumed to occur along with NO oxidation. The equilibrium between NO<sub>2</sub> and  $N_2O_4$  is modelled as two opposing reactions. A rate constant of 10 times the NO oxidation rate constant has been used with satisfactory results.

The formation of nitric acid from water vapor and nitrogen dioxide (Equation 7) is a fast, gas-phase reaction that is effectively at equilibrium. The equilibrium constant of this reaction has been reported in literature (Koukolif M., and Marek J. 1968)

$$3NO_2 + H_2O \implies 2HNO_3 + NO$$

These reactions have been modeled in Fortran subroutine in a plug flow reactor. The NOx reaction model is a kinetic model and will be assumed to take place outside the VLE system. In reality, this approximation leads to reaction in the vapor pipe line and not in a stripper.

#### 1.3 Overall reactions and unknown compounds

Regarding the compounds used,  $H_2SiF6$  is not available in ASPEN. This has been added as a user defined component. The enthalpy of formation is assumed to be zero. Another component that is unavailable in ASPEN is SiO<sub>2</sub> liquid (in solution). The enthalpy of formation is taken same as that of SiO<sub>2</sub>(s).

 $O_2$ ,  $CO_2$ ,  $CI_2$ , HCIO, NH<sub>3</sub>, HCI, N<sub>2</sub>, NO<sub>2</sub>, NO and N<sub>2</sub>O<sub>4</sub> are treated as Henry's components. Henry's law constants are available for all other than N<sub>2</sub>O<sub>4</sub> in Aspen Plus. For N<sub>2</sub>O<sub>4</sub> the constant was obtained from literature (Schwartz, S. E., White W. H, 1981).

There are 14 equilibrium reactions, 3 dissociation reactions and 1 salt formation. The reactions are tabulated in Table 1. Equilibrium data for reactions i-x are available in ASPEN. For xi, xii and xiv the literature data has been used to regress. For reaction xiii the equilibrium data is calculated in ASPEN based on the heats of formation of the individual ions. For reaction iv, the equilibrium parameter is further tuned with literature values. The aspen parameters that were regressed listed in Table 2.

Reactions in Table 1 are all in Liquid phase. The gas phase reactions have been discussed in Section 2.2.

# 2. Results and Discussion

Data Regression in ASPEN PLUS with literature data is used to tune the model and predict thermodynamic coefficients. In this section, the results of the data regression runs are discussed for HF-H<sub>2</sub>O VLE system, HF-SiF<sub>4</sub>-H<sub>2</sub>SiF<sub>6</sub> system and SiO<sub>2</sub> precipitation. The list of all the data obtained via regression is tabulated in Table 2.

326

Sno	Type of Reaction	Reaction	Data in ASPEN
i	Equilibrium	H <sub>2</sub> O + HCLO <> CLO- + H <sub>3</sub> O+	Yes
ii	Equilibrium	2 H <sub>2</sub> O + CL <sub>2</sub> <> HCLO + CL- + H3O+	Yes
iii	Equilibrium	$HNO_3 + H_2O <> H_3O^+ + NO_3^-$	Yes
iv	Equilibrium	HF + H2O <> F <sup>-</sup> + H <sub>3</sub> O+	Yes
V	Equilibrium	$HCL + H2O <> CL^{-} + H_{3}O^{+}$	Yes
vi	Equilibrium	NH <sub>3</sub> + HCO <sub>3</sub> <sup>-</sup> <> H <sub>2</sub> O + NH <sub>2</sub> COO <sup>-</sup>	Yes
vii	Equilibrium	$NH_3 + H_2O \iff OH^- + NH_4^+$	Yes
viii	Equilibrium	$H_2O + HCO_{3^-} - CO_{3^-} + H_3O^+$	Yes
ix	Equilibrium	2 H <sub>2</sub> O + CO <sub>2</sub> <> HCO <sub>3</sub> - + H <sub>3</sub> O <sup>+</sup>	Yes
х	Equilibrium	$2 H_2 O <> OH^- + H_3 O^+$	Yes
xi	Equilibrium	2 H <sub>2</sub> O + SIF <sub>4</sub> <> 4 HF + SIO <sub>2</sub>	No – Regressed
xii	Equilibrium	$2 \text{ HF} + \text{SIF}_4 + 2 \text{ H}_2\text{O} <> 2 \text{ H}_3\text{O}^+ + \text{SIF}_6^{2-}$	No – Regressed
xiii	Equilibrium	CI- + NO <sub>3</sub> - <> CIO- + NO <sub>2</sub> -	No – Approximated from ASPEN
xiv	Equillibrium	SiO <sub>2</sub> + 2H <sub>2</sub> O <-> H <sub>3</sub> O+ + HSiO <sub>3</sub> -	No - Regressed
xv	Salt	SiO <sub>2</sub> (s) <-> SiO <sub>2</sub>	No – Regressed
xvi	Dissociation	$H_2SIF_6 \rightarrow 2 HF + SIF_4$	N/A
xvii	Dissociation	NaOH> $OH^-$ + $Na^+$	N/A
xviii	Dissociation	$KOH> OH^- + K^+$	N/A

Table 1: Overview of the liquid phase reactions

Table 2: List of parameters regressed

S NO	System	Parameter Regressed	Value
1	$H_2O$ and $H_3O^+-SiF_6^{2-}$	GMELCC/1	13.9
2	$H_3O^+$ -SiF <sub>6</sub> <sup>2-</sup> and $H_2O$	GMELCC/1	-6.16
3	Equation xi	K-STOIC/1	-15.8
4	Equation xii	K-STOIC/1	-37.9
5	Equation xv	K-SALT	-3.88
6	Equation xiv	K-STOIC/1	-34
7	SiO <sub>2</sub> -H <sub>2</sub> O	NRTL	Aij: 4, Cij: 0.3
8	$H_2O$ and $H_3O^+-F^-$	GMELCC/1	7.5
9	$H_3O^+$ - $F^-$ and $H_2O$	GMELCC/1	-3.4
10	HF and H <sub>3</sub> O <sup>⁺</sup> -F <sup>-</sup>	GMELCC/1	7.3
11	H₃O <sup>+</sup> -F⁻ and HF	GMELCC/1	-4.2
12	Equation x	K-STOIC/1	A: -9.23, B: 2883.99

GMELCC - Electrolyte-molecule/electrolyte-electrolyte binary energy parameter C in the electrolyte NRTL activity coefficient model.

K-Stoic - Equilibrium constants for equilibrium ionic reaction. Ln(K)=A+ B/T +  $C^{*}In(T) + D^{*}T$ 

Equilibrium constants for salt precipitation reaction. Ln(K)=A+B/T + C\*In(T) + D\*T

#### 2.1 HF-H<sub>2</sub>O system

The ELECNRTL property method is used for predicting the thermodynamic properties. The VLE of HF-H<sub>2</sub>O system predicted from ELECNTRL is fine tuned with literature data from multiple sources. The literature data (directly imported from NIST database) is used to regress the electrolyte pair parameter as well as the kinetic parameter of the reaction (iv). The effect of temperature on HF-H<sub>2</sub>O VLE at very low concentrations is well captured in the model.



In Figure 1, the x-axis has represents the weight fraction of HF and the y-axis represents the partial pressure of HF in the gas phase.

Figure 1:The VLE data of HF-H2O at different temperatures (Brosheer, J. C et.al, 1947)





Figure 2: VLE(2) of HF-SiF4 -H2SiF6 System in semi-log scale.

328

#### 2.2 HF-SiF<sub>6</sub>-H<sub>2</sub>SiF<sub>6</sub> system

The HF-SiF<sub>4</sub> system as seen from Section 2.1 is quite complex. The literature date is used to regress and obtain thermodynamic constants for electrolyte pair parameter and kinetic parameter for reactions xi, xii. The results of the various data-regression studies on this system are discussed in Section 2.1. Figure 2 and Figure 3 show the comparison of the literature data with the model prediction. Figure 2 the data points are from literature source while the straight lines are results of the model. Some of the inferences about this system from these graphs are :,

- HF is the more volatile component amongst HF and SiF<sub>4</sub>.
- The H<sub>2</sub>SiF<sub>6</sub> is a very strong acid. This effect is very well captured in the model (From Figure 3), though direct dissociation of H<sub>2</sub>SiF<sub>6</sub>. H<sub>2</sub>SiF<sub>6</sub> as pure component is not part of the model.
- The effect of temperature on the VLE system is well captured in the model.
- There is an apparent sudden increase in the vapor pressures of SiF<sub>4</sub> at low concentrations of H<sub>2</sub>SiF<sub>6</sub>.
- There is a difference in the prediction of the pH from Figure 3. Possible reason could be, that even at the lower concentrations the polar effects of dissociation from equation ix and x are higher than equilibrium predictions. For the purposes of modelling an industrial scrubber this is considered sufficient as the difference is within the margin taken for design.



Figure 3: Comparison of H<sub>2</sub>SiF<sub>6</sub> pH



Figure 4: Solubility of SiO<sub>2</sub> in a solution of  $H_2SiF_6$  (Thomsen S.M., 1952)

# 2.3 SiO<sub>2</sub> Precipitation

The literature data is used to predict the kinetic parameters for the equations (xiv) and (xv). The behaviour of  $SiO_2$  precipitation is well captured as shown in Figure 4. The y axis shows the molality of  $SiO_2$ , which is a measure of  $SiO_2$  in liquid. In Figure 4 the data at higher molality of  $H_2SiF_6$  is not considered as it is not expected to be seen in the real industrial process. From Figure 4, the solubility at higher concentrations are not accurately captured due to the lack of experimental points.

# 3. Limitations of the model

Based on the above analysis, the following limitations are noted:

- The gas phase oxidation of NO to NO<sub>2</sub> takes place only in a plug flow reactor.
- The enthalpy of formation of SiO<sub>2</sub> is unknown and is approximated to the enthalpy of formation of SiO<sub>2</sub>(s). This approximation could result in an inaccurate temperature prediction.
- At the very low concentration that is prevalent in the current system, the hexamerization is insignificant. Hence ELECNRTL property method is used and not ELECNRTL-HF
- The solubility of SiO<sub>2</sub> at higher pH could be an over prediction as there is no literature or experimental data to validate the model,

# 4. Conclusion

A thermodynamic model has been developed with the help of Data regression system available in ASPEN PLUS with the following features:

- Accurate representation of HF-H<sub>2</sub>O binary system at low temperature and lower concentrations.
- Accurate representation of absorption of SiF<sub>4</sub> and HF in water, accurately capturing the equilibrium between SiF<sub>4</sub>-HF-H<sub>2</sub>O in gas and liquid phase along with reactive SiO<sub>2</sub>.
- Accurate representation of solubility of SiO<sub>2</sub> in aqueous solution.
- A simple model for NOx absorption.

Thus the developed model in spite of the inherent limitations can be used a good starting point for simulating absorption. The developed thermodynamic model was successfully used in scrubber simulation.

#### References

AspenTech, home.aspentech.com/products/engineering/aspen-plus

Bodenstein, M Z. Physik. Chem. 100, 118, 1922

Brosheer, J. C., Lenfesty, F. A., and Elmore, K. L., 1947, Industrial. Engnieering. Chemistry., Vol. 39

Chen, C.-C., Britt H. I., Boston J. F., and Evans L. B., 1982 "Local Com-position Model for Excess Gibbs Energy of Electrolyte Sys-tems," AIChE Journel., 28, 588.

Iler, R K, Chemistry of Silica - Solubility, Polymerization, Colloid and Surface Properties and Biochemistry",

Illarionov, V. V.; Smirnova, Z. G.; Knyazeva, K. P. 1963, Partzial'nye ravnovesnye davleniya HF, SiF4 i H2O nad vodnymi rastvorami kremneftoristovodorodnoi kisloty Zeitschrift für anorganische und allgemeine Chemie, 559 (1), 27-39 Zh. Prikl. Khim., 36 (), 237-241

Kohl A.L., Nielson R., 1997, Gas Purification 5<sup>th</sup> Edition, Gulf Professional publishing. Pg 439.

Koukolif M., and Marek J,1968, Mathematical Model of HNO<sub>3</sub> Oxidation-absorption Equipment," Proc. Fourth European Symp. On Chem. Reac. Eng.

Schwartz, S. E., White W. H, Adv. Environ. Sci. Eng., 4, 1 (1981)

Thomsen S.M., 1952," High-silica Fluosilicic Acids: Specific Reactions and the Equilibrium with Silica", Journal. of American. Chemistry. Society 74 (7), pp 1690–1693,

330